

SM6S10AHM3 thru SM6S43AHM3

Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218 Compatible

Anode O Cathode

LINKS TO ADDITIONAL RESOURCES





Pac

| PRIMARY CHARACTERISTICS | | | | | | | |
|-----------------------------------|------------------|--|--|--|--|--|--|
| V _{WM} | 10 V to 43 V | | | | | | |
| V _{BR} | 11.1 V to 52.8 V | | | | | | |
| P _{PPM} (10 x 1000 μs) | 4600 W | | | | | | |
| P _{PPM} (10 x 10 000 μs) | 3600 W | | | | | | |
| PD | 6 W | | | | | | |
| I _{FSM} | 600 A | | | | | | |
| T _J max. | 175 °C | | | | | | |
| Polarity | Unidirectional | | | | | | |
| Package | DO-218AC | | | | | | |

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement
- Unidirectional
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 HM3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | | | |
|------------------------------------------------------------------------|-----------------------------------------|-----------------------------------|----------------|------|--|--|--|--|--|
| PARAMETER | | SYMBOL | VALUE | UNIT | | | | | |
| Peak pulse power dissipation | with 10/1000 µs waveform | Р | 4600 | W | | | | | |
| | with 10/10 000 µs waveform | PPPM | 3600 | vv | | | | | |
| Power dissipation on infinite heats | sink at T _A = 25 °C (fig. 1) | PD | 6.0 | W | | | | | |
| Peak pulse current with 10/1000 | us waveform | I _{PPM} ⁽¹⁾ | See next table | А | | | | | |
| Peak forward surge current 8.3 m | s single half sine-wave | I _{FSM} | 600 | A | | | | | |
| Operating junction and storage te | mperature range | T _J , T _{STG} | -55 to +175 | °C | | | | | |

Note

⁽¹⁾ Non-repetitive current pulse at $T_A = 25 \ ^{\circ}C$

RoHS COMPLIANT

HALOGEN FREE





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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | | | | |
|----------------------------------------------------------------------------|---------------------------------------------|------|------|------------------------|------------------------|--------------------|-------------------------------|----------------------------------|------------------------------------------------------|----------------------------------------------|
| | BREAKDOWN VOLTAGE V _{BR} (V) | | | TEST CURRENT | STAND-OFF VOLTAGE | MAXIMUM REVERSE | MAXIMUM REVERSE LEAKAGE | MAX. PEAK PULSE CURRENT | MAXIMUM CLAMPING | TYPICAL TEMP. COEFFICIE |
| DEVICE TYPE | MIN. | NOM | MAX | I _T (mA) | V _{WM} (V) | | | AT 10/1000 μs WAVEFORM (A) | VOLTAGE AT I _{PPM} V _C (V) | NT OF V _{BR} (1) αT (%/°C) |
| SM6S10AHM3 | 11.1 | 11.7 | 12.3 | 5.0 | 10.0 | 15 | 250 | 271 | 17.0 | 0.069 |
| SM6S11AHM3 | 12.2 | 12.9 | 13.5 | 5.0 | 11.0 | 10 | 150 | 253 | 18.2 | 0.072 |
| SM6S12AHM3 | 13.3 | 14.0 | 14.7 | 5.0 | 12.0 | 10 | 150 | 231 | 19.9 | 0.074 |
| SM6S13AHM3 | 14.4 | 15.2 | 15.9 | 5.0 | 13.0 | 10 | 150 | 214 | 21.5 | 0.076 |
| SM6S14AHM3 | 15.6 | 16.4 | 17.2 | 5.0 | 14.0 | 10 | 150 | 198 | 23.2 | 0.078 |
| SM6S15AHM3 | 16.7 | 17.6 | 18.5 | 5.0 | 15.0 | 10 | 150 | 189 | 24.4 | 0.080 |
| SM6S16AHM3 | 17.8 | 18.8 | 19.7 | 5.0 | 16.0 | 10 | 150 | 177 | 26.0 | 0.081 |
| SM6S17AHM3 | 18.9 | 19.9 | 20.9 | 5.0 | 17.0 | 10 | 150 | 167 | 27.6 | 0.082 |
| SM6S18AHM3 | 20.0 | 21.1 | 22.1 | 5.0 | 18.0 | 10 | 150 | 158 | 29.2 | 0.083 |
| SM6S20AHM3 | 22.2 | 23.4 | 24.5 | 5.0 | 20.0 | 10 | 150 | 142 | 32.4 | 0.085 |
| SM6S22AHM3 | 24.4 | 25.7 | 26.9 | 5.0 | 22.0 | 10 | 150 | 130 | 35.5 | 0.086 |
| SM6S24AHM3 | 26.7 | 28.1 | 29.5 | 5.0 | 24.0 | 10 | 150 | 118 | 38.9 | 0.087 |
| SM6S26AHM3 | 28.9 | 30.4 | 31.9 | 5.0 | 26.0 | 10 | 150 | 109 | 42.1 | 0.088 |
| SM6S28AHM3 | 31.1 | 32.8 | 34.4 | 5.0 | 28.0 | 10 | 150 | 101 | 45.4 | 0.089 |
| SM6S30AHM3 | 33.3 | 35.1 | 36.8 | 5.0 | 30.0 | 10 | 150 | 95 | 48.4 | 0.090 |
| SM6S33AHM3 | 36.7 | 38.7 | 40.6 | 5.0 | 33.0 | 10 | 150 | 86 | 53.3 | 0.091 |
| SM6S36AHM3 | 40.0 | 42.1 | 44.2 | 5.0 | 36.0 | 10 | 150 | 79 | 58.1 | 0.091 |
| SM6S40AHM3 | 44.4 | 46.8 | 49.1 | 5.0 | 40.0 | 10 | 150 | 71 | 64.5 | 0.092 |
| SM6S43AHM3 | 47.8 | 50.3 | 52.8 | 5.0 | 43.0 | 10 | 150 | 66 | 69.4 | 0.093 |

Notes

- For all types maximum V_F = 1.9 V at I_F = 100 A measured on 300 μ s square pulse width

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | | |
|--------------------------------------------------------------------------------|---------------------------------|-------|------|--|--|--|--|--|
| PARAMETER | SYMBOL | VALUE | UNIT | | | | | |
| | R _{0JA} ⁽¹⁾ | 55 | °C/W | | | | | |
| Typical thermal resistance | R _{0JM} ⁽²⁾ | 0.45 | °C/W | | | | | |

Notes

(1) Thermal resistance junction-to-ambient to follow JEDEC®51-2A, device mounted on FR4 PCB, 2 oz. standard footprint

(2) Thermal resistance junction-to-mount to follow JEDEC®51-14 using Transient Dual Interface Test Method (TDIM)



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ORDERING INFORMATION TABLE

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| _ | | | | | | | |
|-------------|-----|-------|------------|-------------------|-----------------------|----------|-----------|
| Device code | SM | X | S | XX | A | н | M3 |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| | 1 - | Sur | face mo | unt | | | |
| | 2 - | - Pov | ver dissi | pation F | P _D (5 = 5 | 5 W, 6 = | 6 W, 8 |
| | 3 | - Sta | ndard V | _F type | | | |
| | 4 | - Sta | nd-off v | oltage | | | |
| | 5 - | Bre | akdown | voltage | toleran | ce and p | olarity (|
| | 6 | Qua | ality grad | de (H = | AEC-Q1 | 01 qual | ified, ot |
| | 7 | | | | ient cate nd termi | ••• | |

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|---------------------------------------------------------------------|--|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | | |
| SM6S10AHM3/I ⁽¹⁾ | 2.550 | Ι | 750 | 13" diameter plastic tape and reel, anode towards the sprocket hole | | | | |

Note

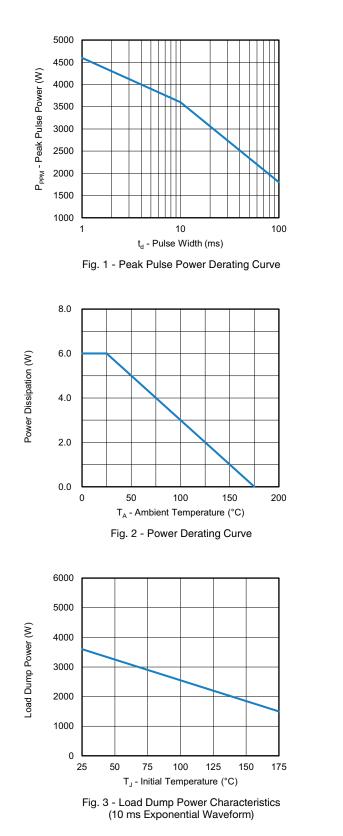
(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)



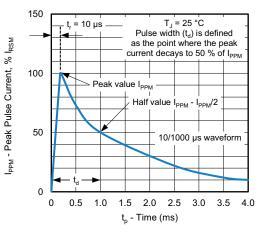


Fig. 4 - Pulse waveform

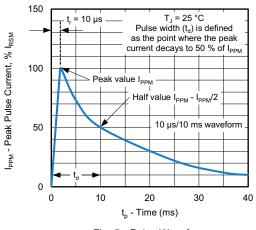


Fig. 5 - Pulse Waveform

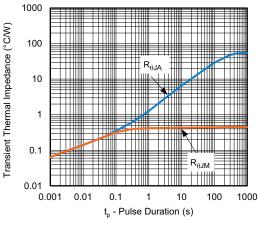


Fig. 6 - Typical Transient Thermal Impedance

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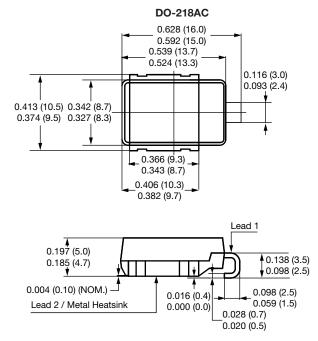
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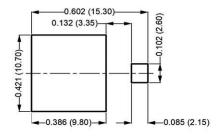
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout



Note

• Footprint in accordance with IPC 7351 standard



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